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Diodes Incorporated DMP21D5UFB4-7B

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DMP21D5UFB4

P-CHANNEL ENHANCEMENT MODE MOSFET

Product Summary

V _{(BR)DSS}	R _{DS(on) max}	I _D T _A = 25°C
	$1.0\Omega @ V_{GS} = -4.5V$	-700mA
-20V	1.5Ω @ V _{GS} = -2.5V	-600mA
	2.0Ω @ V _{GS} = -1.8V	-500mA
	3.0Ω @ V _{GS} = -1.5V	-380mA

Description and Applications

This new generation MOSFET has been designed to minimize the onstate resistance (R_{DS(on})) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- **DC-DC Converters**
- Power management functions

Features and Benefits

- Low On-Resistance
- Very Low Gate Threshold Voltage V_{GS(TH)}, 1.0V max
- Low Input Capacitance
- Fast Switching Speed
- Ultra-Small Surfaced Mount Package
- Ultra-low package profile, 0.4mm maximum package height **ESD** Protected Gate
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- Qualified to AEC-Q101 Standards for High Reliability

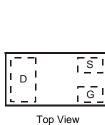
Mechanical Data

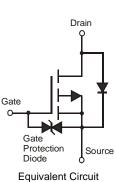
- Case: X2-DFN1006-3
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish NiPdAu over Copper leadframe. Solderable per MIL-STD-202, Method 208
- Weight: 0.001 grams (approximate)





X2-DFN1006-3





Internal Schematic

Ordering Information (Note 4)

Part Number	Case	Packaging
DMP21D5UFB4-7B	X2-DFN1006-3	10,000/Tape & Reel

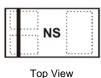
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant.

2. See http://www.diodes.com for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free. 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at http://www.diodes.com.

Marking Information

Notes:



Bar Denotes Gate and Source Side

NS = Product Type Marking Code





DMP21D5UFB4

Maximum Ratings @T_A = 25°C unless otherwise specified

Characteristic	Symbol	Value -20	Units V V		
Drain-Source Voltage	V _{DSS}				
Gate-Source Voltage				V _{GSS}	±8
	Steady State	T _A = 25°C T _A = 70°C	ID	-700 -600	mA
Continuous Drain Current (Note 6) V_{GS} = -4.5V	t<10s	T _A = 25°C T _A = 70°C	ID	-850 -670	mA
	Steady State	T _A = 25°C T _A = 70°C	ID	-500 -400	mA
Continuous Drain Current (Note 6) V_{GS} = -1.8V	t<10s	T _A = 25°C T _A = 70°C	ID	-600 -550	mA
Pulsed Drain Current (10µs pulse, duty cycle = 1%)			I _{DM}	-2	А
Maximum Body Diode continuous Current			ls	-800	mA

Thermal Characteristics @T_A = 25°C unless otherwise specified

Characteristic		Symbol	Value	Units
Total Power Dissipation (Note 5)		PD	0.46	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady state	D	279	°C/W
	t<10s	$R_{ heta}JA$	210	°C/W
Total Power Dissipation (Note 6)		PD	0.95	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady state	Р	134	°C/W
Thermal Resistance, Junction to Ambient (Note 6)	t<10s	$R_{ heta JA}$	100	°C/W
Operating and Storage Temperature Range		T _J , T _{STG}	-55 to +150	°C

Electrical Characteristics $@T_A = 25^{\circ}C$ unless otherwise specified

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 7)							
Drain-Source Breakdown Voltage	BV _{DSS}	-20	-	-	V	$V_{GS} = 0V, I_D = -1mA$	
Zero Gate Voltage Drain Current T _J = 25°C	I _{DSS}	-	-	-100	nA	$V_{DS} = -20V, V_{GS} = 0V$	
Gate-Source Leakage		-	-	±1.0	μA	$V_{GS} = \pm 5V, V_{DS} = 0V$	
Gale-Source Leakage	I _{GSS}	-	-	±5.0		$V_{GS} = \pm 8V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 7)							
Gate Threshold Voltage	V _{GS(th)}	-0.5	-	-1.0	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	
		-	0.67	0.97		$V_{GS} = -5V, I_D = -100mA$	
			0.7	1.0		$V_{GS} = -4.5V, I_D = -100mA$	
Static Drain-Source On-Resistance	Pro (au)	-	0.9	1.5	Ω	$V_{GS} = -2.5V, I_D = -80mA$	
Static Drain-Source On-Resistance	R _{DS} (ON)	-	1.2	2.0	52	$V_{GS} = -1.8V, I_D = -40mA$	
		-	1.5	3.0		$V_{GS} = -1.5V, I_D = -30mA$	
		-	5	-		$V_{GS} = -1.2V, I_D = -1mA$	
Forward Transfer Admittance	Y _{fs}	-	0.7	-	S	$V_{DS} = -3V, I_{D} = -100mA$	
Diode Forward Voltage	V _{SD}	-	-0.75	-1.2	V	$V_{GS} = 0V, I_{S} = -330mA,$	
DYNAMIC CHARACTERISTICS (Note 8)							
Input Capacitance	Ciss	-	46.1	-			
Output Capacitance	Coss	-	7.2	-	pF	$V_{DS} = 10V, V_{GS} = 0V,$ f = 1.0MHz	
Reverse Transfer Capacitance	C _{rss}	-	4.9	-		1 - 1.00012	
Gate Resistance	Rg	-	14.3	-	Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge V _{GS} = -4.5V	Qg	-	0.5	-			
Gate-Source Charge	Q _{gs}	-	0.09	-	nC	$V_{DS} = -10V, I_D = -250mA$	
Gate-Drain Charge	Q _{gd}	-	0.09	-			
Turn-On Delay Time	t _{D(on)}	-	8.5	-			
Turn-On Rise Time	tr	-	4.3	-		$V_{DD} = -3V, V_{GS} = -2.5V,$	
Turn-Off Delay Time	t _{D(off)}	-	20.2	-	ns	$R_L = 300\Omega, R_G = 25\Omega,$ $I_D = -100mA$	
Turn-Off Fall Time	t _f	-	19.2	-			

5. Device mounted on FR-4 substrate PC board, 2oz copper, with minimum recommended pad layout. Notes:

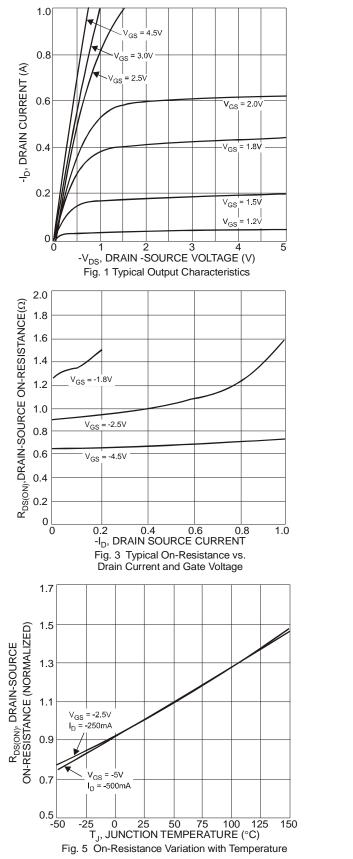
6. Device mounted on FR-4 substrate PC board, 2oz copper, with 1inch square copper plate.

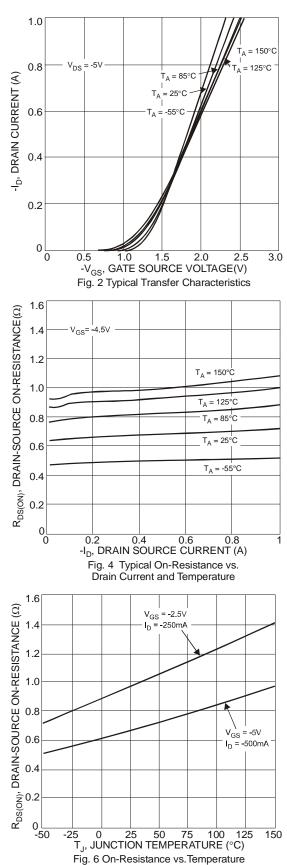
Short duration pulse test used to minimize self-heating effect.
Guaranteed by design. Not subject to product testing.





DMP21D5UFB4

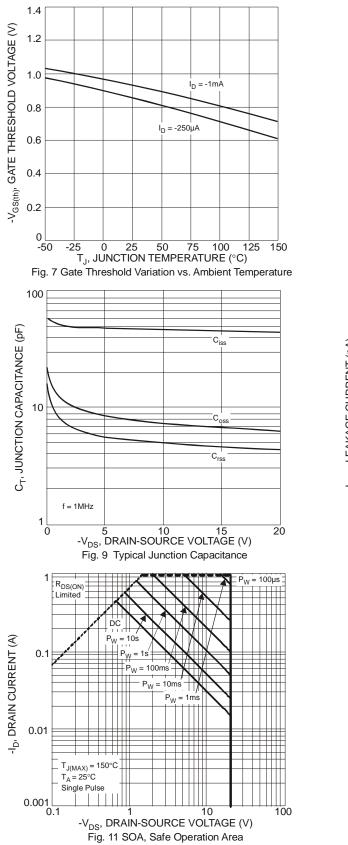


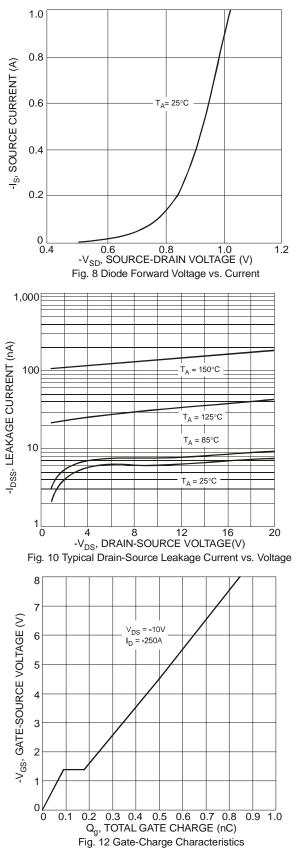






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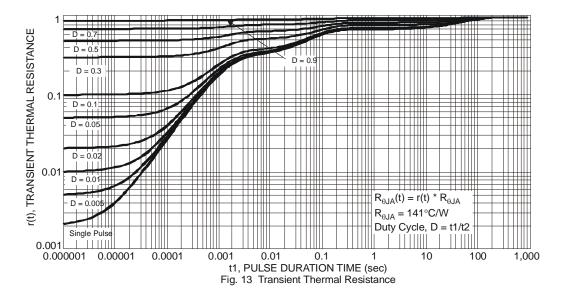


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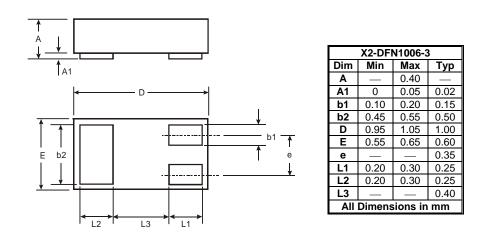




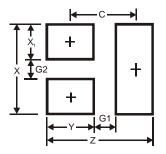
DMP21D5UFB4



Package Outline Dimensions



Suggested Pad Layout



Dimensions	Value (in mm)
Z	1.1
G1	0.3
G2	0.2
Х	0.7
X1	0.25
Y	0.4
С	0.7

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